Development of a Compact Low-Temperature Co-Fired Ceramic Antenna Front-End Module

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Abstract—This study proposes a compact 5-GHz front-end module with embedded antenna on a low-temperature co-fired ceramic substrate, which is to be used for the IEEE 802.11a wireless local area network applications. The module comprises an embedded inverted-F antenna, a bandpass filter, and a low-pass filter. Both the proposed filters possess transmission zeros at out band for suppressing unwanted signals. A double-pole double-throw bare die transmitting/receiving switch is mounted on the surface of the substrate. The interconnection between the bare die switch and the buried circuits is established by bond wires. The effect of the bond wire is considered by incorporating its equivalent inductance into the design of the filters. The overall size of the antenna front-end module is only 6.2 mm imes 5.4 mm imes 0.98 mm with most of the space (near two-thirds of the volume) reserved for the antenna so as to have a better radiation performance. Also, to avoid the potential close proximity coupling among the buried circuits and the antenna, numerous metal vias connecting the top and bottom grounds in the module are designed for shielding. Since the radiation of a small antenna is influenced by the nearby circuit ground due to induced ground current, the developed antenna front-end module is tested on two FR4 printed circuit boards (PCBs) with different sizes (i.e., 55 mm × 20 mm and 80 mm imes 46 mm). It is demonstrated that the antenna module performs well on these two grounded PCBs. The achieved 10-dB return-loss bandwidths are near 900 MHz for the transmitting and receiving paths. The measured radiation patterns are quite omnidirectional with peak gains (including the losses of circuit components) at approximately 0 dBi for the transmitting path and $-1.\overline{7}$ dBi for the receiving path.

Index Terms—Inverted-F antenna, low-temperature co-fired ceramic (LTCC), RF front-end module, system-on-package (SOP), wireless local area network (WLAN).

I. INTRODUCTION

RECENTLY, the wireless local area network (WLAN) systems have been widely used in handheld devices such as notebooks and personal digital assistants (PDAs). The size and weight of the components are important factors in the product development. The "system-on-package" (SOP) is an important concept to implement a miniature circuitry, which integrates many active and passive devices of a functional system or

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subsystem into one package [1], [2]. By properly designing on multilayer substrate such as low-temperature co-fired ceramic (LTCC), we can integrate active devices (power amplifiers, low-noise amplifiers, and transmitting/receiving (T/R) diversity switches) and buried passive devices (low-pass filters, bandpass filters, baluns, diplexers, matching networks, and even antennas) into a package. The LTCC technology is used widely in multilayer substrate for designing a miniature RF passive component, due to low tolerance in dielectric constant, high degree of integration, and feasibility for multilayer circuit design.

In this study, we develop an RF front-end antenna switch module using LTCC, which is to be applied in the IEEE 802.11a WLAN. Following the IEEE 802.11a standard, the RF front-end modules using LTCC technology have been presented in [3]–[6], where only the filters and active devices were integrated in the module. Different from the authors' prior works, the RF front-end antenna switch module proposed here possesses a higher integration level, including not only the passive circuit components (a bandpass filter and low-pass filter) and active device (a double-pole double-throw (DPDT) T/R switch), but also an embedded antenna.

Although the LTCC-based antenna front-ends have been published in recent years, most of them operated at the millimeterwave frequency [7]-[9]. The component design and circuit integration were straightforward, resulting in a large module size as compared to the wavelength. For the microwave application, due to the long wavelength, the module needs to be designed in a miniature size. This implies that the buried components would be crowded in the high dielectric-constant material. The coupling among circuits and the antenna should thus be carefully handled to retain each component's function. Recently, a microwave antenna integrated LTCC module has been developed for the Bluetooth application [10], which achieved a compact size (12 mm \times 12 mm), as compared to the wavelength at 2.4 GHz. However, the antenna performance, especially the radiation pattern, was not checked. The influence of the size of the printed circuit board (PCB) on the antenna characteristics was also not considered.

The block diagram of the 5-GHz antenna switch module to be developed in this paper is shown in Fig. 1(a). The two filters and the antenna are buried in the LTCC substrate, while the bare-die DPDT T/R switch is mounted on the top surface of the LTCC substrate. Note that for suppressing the harmonic signals from the power amplifier (not included in the present module) while remaining a minimum insertion loss, a low-pass filter, instead of a bandpass filter, is used in the transmitting path.

The interconnection between the switch and antenna, as well as that between the switch and buried circuits, are established

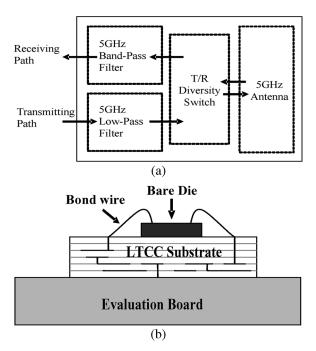


Fig. 1. (a) Block diagram of the proposed RF front-end antenna switch module. (b) Side view of the bare die, bond wires, and buried circuits.

by bond wires, as shown in Fig. 1(b). Since the bond wire behaves as an inductor in the high-frequency range, we have to take its effect into consideration [11]–[13] so as to improve the impedance matching of the buried circuit. In this paper, we consider the effect of the bond wire by incorporating it into the design of the bandpass filter and low-pass filter. The filters were designed and simulated using Ansoft Corporation's full-wave electromagnetic (EM) High Frequency Structure Simulator (HFSS) simulator [14] and Applied Wave Research Inc.'s Microwave Office circuit simulator [15]. The experimental and simulation results are presented in each section.

II. DESIGN OF COMPONENTS

The receiving path of the 5-GHz antenna switch module is composed of an antenna, a DPDT switch, and a bandpass filter, while the transmitting path is composed of a low-pass filter, the DPDT switch, and the antenna. There are 14 layers (seven thin layers and seven thick layers) used in the LTCC substrate for all the components.

In the development of the antenna switch module, there were totally four types of the LTCC modules fabricated for the test purpose. The four modules contain all the buried components (i.e., the bandpass filter, low-pass filter, and antenna), but with different output ports. Modules 1 and 2 have two output ports, which were built for testing the performances of the bandpass filter and low-pass filter, respectively. The two output ports of these modules were connected to the filter ports by additional $50-\Omega$ lines in the LTCC. All the other components were left floating. Fig. 2 presents the photograph of the test fixture for modules 1 and 2. Module 3 was fabricated for antenna testing, which has a single output port connected to the buried antenna in the LTCC. Note that although without the DPDT switch in these three modules, the bond wire associated with each passive

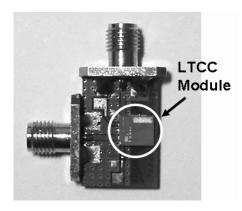


Fig. 2. Test fixture for modules 1 and 2.

TABLE I FOUR RF FRONT-END MODULES FOR TESTING

Module	Included Components	No. of Output Ports
1	Band-pass filter + Bond wire	2
2	Low-pass filter + Bond wire	2
3	Antenna + π -matching Circuit + Bond wire	1
4	Antenna + Switch + LPF (Tx) Antenna + Switch + BPF (Rx)	3

Tx = Transmitting Path, Rx = Receiving Path.

component was reserved since its effect had been considered in the component design. Finally, module 4 is the complete antenna switch module including the buried passive components, the DPDT switch, and the connecting bond wires. This module has three output ports, the first corresponding to the transmitting path, the second to the receiving path, and the third reserved for an external antenna for diversity application. Table I summarizes the four types of the modules. More details about the modules will be revealed in the following.

A. Bandpass Filter

The proposed bandpass filter uses inductors as the impedance transformer at the I/O ports instead of capacitors in most bandpass filter configurations [16]–[19]. The inductor can be implemented by an external bond wire or internal buried circuits.

The schematic of the new bandpass filter for the module is shown in Fig. 3(a). It is a third-order filter with one parallel LC resonator (formed by striplines L_5 and L_7 and capacitor C_5) and two equivalent parallel LC resonators, which are composed of two series LC resonators (L_3 , C_3 , and L_4 , C_4) and two open-end stripline stubs (L_1 , L_2). The two series LC resonators can provide finite transmission zeros at lower frequencies. In the passband, these resonators behave as inductors, which are shunt to the two capacitive striplines L_1 and L_2 , thus generating two transmission poles. In addition, the striplines L_1 and L_2 are open-end stubs with different length, which are quarter-wavelength resonators providing two transmission zeros at higher frequencies (near the second harmonics of the operating frequencies). Moreover, the series LC resonator (L_7 , C_5) can provide the third transmission zero at a higher frequency.

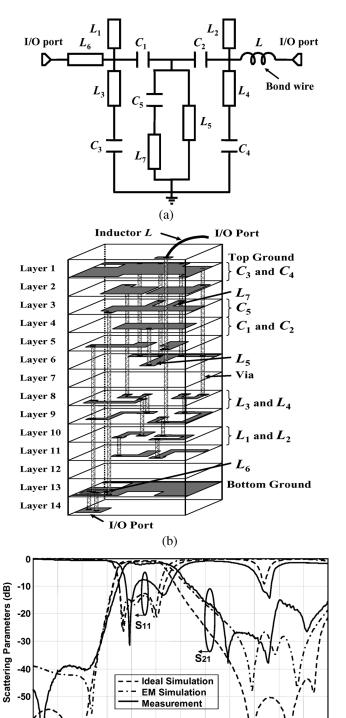


Fig. 3. (a) Schematic of the proposed bandpass filter. (b) 3-D layout of the bandpass filter. (c) Simulated and measured *S*-parameters of the bandpass filter.

Frequency (GHz)

(c)

The capacitors C_1 and C_2 are admittance inverters used to control the coupling between the LC resonators and act together with C_3 and C_4 as dc-decoupling capacitors to block the dc signals before and after the filter. The stripline L_6 acts as an impedance transformer matching the resonators to the external

TABLE II CORRESPONDING COMPONENT VALUES FOR THE BANDPASS FILTER

Component	Value	Component	Value
$C_1 = C_2(pF)$	0.668	$L_3 = L_4 (\mu \text{ m}^2)$ (width × length)	100 × 2220
$C_3 = C_4 (pF)$	2.59	$L_5(\mu \text{ m}^2)$ (width × length)	152 × 675
C ₅ (pF)	1.61	$L_6(\mu \mathrm{m}^2)$ (width × length)	100 × 500
$L_1(\mu \text{ m}^2)$ (width × length)	150 × 2272	$L_7(\mu \text{ m}^2)$ (width × length)	100 × 198
$L_2(\mu \mathrm{m}^2)$ (width × length)	150 × 2634	-	-

impedance, as does the inductor L. Notably, the inductor L (approximately 1 nH) is not buried in the LTCC substrate, but implemented utilizing an external bond wire, which is used to connect the bandpass filter and the top-surface bare die (the DPDT T/R switch). The corresponding component values are listed in Table II.

The 3-D layout of the bandpass filter is shown in Fig. 3(b). 14 layers are used. The thicknesses of the first layer and the eighth to thirteenth layers are all equal to 0.09 mm, and those of other layers are 0.04 mm. The bandpass filter was fabricated in module 1 using the Dupont 951 LTCC process with a substrate dielectric constant of 7.8. The commonly used FR4 PCB with a dielectric constant of 4.4, loss tangent of 0.02, and thickness of 0.8 mm, is used as the evaluation board (Fig. 2) for measuring the performance of the fabricated LTCC filter.

The measured S-parameters, as well as the ideal circuit simulation and EM simulation results, are shown in Fig. 3(c). The measured results agree with the EM simulations, but exhibit only two poles in the passband due to the inaccuracy of the LTCC process. The inaccuracy also deteriorates the return loss in the passband and results in the discrepancy between the measurement and simulation in the higher stopband. The reason for the inaccuracy is that during the LTCC firing process, there is tape shrinkage between 10%-5% occurring in the length and width dimensions and slightly in the height. It will change the capacitance and inductance in the LTCC module and cause the discrepancies between the EM simulation and measurement. Nevertheless, the measured insertion losses from 4.85 to 6 GHz are less than 2.31 dB with a minimum value of 1.5 dB at 4.92 GHz. Both the transmission zeros at the higher frequencies of 8.92 and 10.5 GHz provide suppression near 38 dB. In addition, the suppression in the range of 1-3 GHz is higher than 38.7 dB.

B. Low-Pass Filter

The schematic of the proposed low-pass filter incorporating the bond wire is shown in Fig. 4(a). The low-pass filter has six elements with two transmission zeros in the stopband. The inductor L was implemented utilizing the external bond wire, which was used to connect the low-pass filter and the top-surface bare die (the DPDT T/R switch). Since the short stripline L_1 of low characteristic impedance can be represented by a T-equivalent circuit [20], as shown in Fig. 4(b), the stripline L_1 in shunt

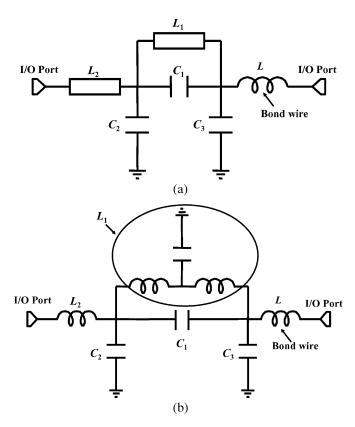


Fig. 4. (a) Schematic of the proposed low-pass filter. (b) Equivalent circuit of the low-pass filter.

TABLE III
CORRESPONDING COMPONENT VALUES FOR THE LOW-PASS FILTER

Component	Value	Component	Value
<i>C</i> ₁ (pF)	0.3	$L_1 (\mu \text{ m}^2)$ (width × length)	184 × 2629
C ₂ (pF)	0.2	$L_2 (\mu \text{ m}^2)$ (width × length)	184 × 4550
C ₃ (pF)	0.44	-	-

with the capacitor C_1 would be resonant at two higher frequencies, thus producing two transmission zeros. By changing the length of the stripline L_1 or the value of the capacitor C_1 , we can control the frequency locations of the two zeros. The corresponding component values are listed in Table III.

The 3-D layout of the proposed low-pass filter is shown in Fig. 5(a). Since the filter has only five buried elements, we use three layers (eighth to tenth layers) for this layout. In order to reduce the fabrication inaccuracy affecting the filter performance, the thick layers were used for enhancing the capacitance tolerance.

The measured results with a bond wire (using module 2) are depicted in Fig. 5(b). The simulation results are also shown for comparison. There is a small discrepancy between the measurement and simulation in the higher stopband due to the inaccuracy of the LTCC process. The measured insertion losses from 4.9 to 6 GHz were less than 1.57 dB with a minimum value of 0.95 dB at 5.3 GHz. Moreover, the transmission zeros at

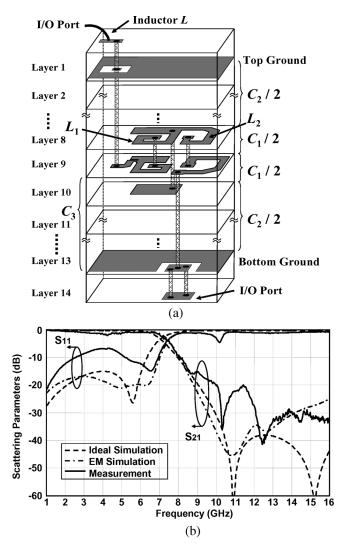


Fig. 5. (a) 3-D layout of the low-pass filter. (b) Simulated and measured S-parameters of the low-pass filter.

10.3 and 12.4 GHz provide suppressions of 35.6 and 41.4 dB, respectively.

C. DPDT T/R Switch

A DPDT T/R switch is used to switch the antenna port to the bandpass filter or the low-pass filter for receiving or transmitting signals, respectively. The requirement of the switch is low insertion loss at operating band and high rejection between the through and isolation ports. In order to miniaturize the entire module, a GaAs pseudomorphic HEMT (pHEMT) monolithic microwave integrated circuit (MMIC) DPDT bare die switch [21] is used for the module integration. The size of the bare die switch is 0.99 mm \times 0.93 mm. The insertion loss and isolation at the operating frequencies (4.85–6 GHz) are around 1 and 25 dB, respectively.

D. Embedded 5-GHz Antenna

An embedded 5-GHz antenna was designed in the LTCC multilayer substrate. The antenna is required to have input impedance near 50 Ω for good return loss and possess proper antenna gain (with peak gain larger than 0 dBi). The radiation

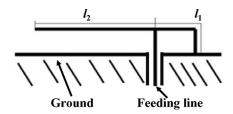


Fig. 6. Structure of the inverted-F antenna.

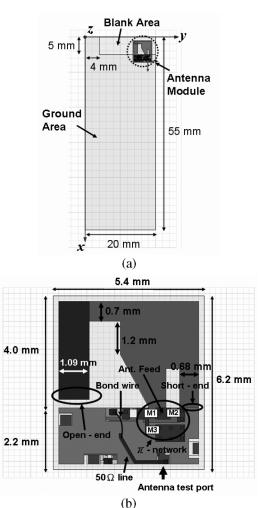


Fig. 7. (a) Geometry of the small PCB containing the antenna switch module. (b) Size of the 5-GHz antenna in the LTCC module. Ant. Feed = antenna feed.

patterns should be as omnidirectional as possible at the operating frequencies. The antenna designed for this module is based on the inverted-F antenna shown in Fig. 6, where l_1 and l_2 are the lengths of the short- and the open-circuited strips. For resonance, the electrical length of $l_1 + l_2$ should be near 90° at the operating frequency [22].

The present antenna switch module is proposed for use on a small FR4 PCB with size of 55 mm \times 20 mm (the typical size for a USB dongle) in which the substrate ground occupies an area of (50 mm \times 20 mm + 5 mm \times 4 mm), as shown in Fig. 7(a). The LTCC antenna module (module 3) with area of 6.2 mm \times 5.4 mm [see Fig. 7(b)] is to be placed on the corner of the substrate (the blank area), with the circuit portion (filters and

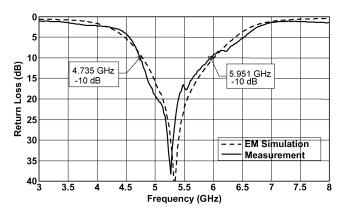


Fig. 8. EM simulated and measured return losses $(1/S_{11})$ of the embedded inverted-F antenna on the PCB with size of 55 mm \times 20 mm.

switch) intruding into the ground area. The antenna occupies an area of 4 mm \times 5.4 mm.

The EM simulator (HFSS) was used to simulate and design the 3-D LTCC embedded antenna. The resultant antenna structure, as shown in Fig. 7(b), is little dissimilar to a typical inverted-F antenna in the antenna's right half part (including the area around the antenna feed and short end) due to the consideration of impedance matching. However, this area, like a conventional inverted-F antenna, still contributes most of the antenna's radiation field since large induced current distributed around it. Also, in order to reduce the antenna size, the open-circuited end of the inverted-F antenna is bent downward. The antenna was built on only two layers. The bent open-circuited end was placed on the top surface of the module, and the other portion of the antenna was on the second layer, with vertical via connecting them. We may tune the antenna resonance frequency by cutting the open-circuited end if the frequency is shifted downward due to the fabrication inaccuracy. The electrical length of $l_1 + l_2$ equals 12.3 mm and the other dimensions are shown in Fig. 7(b). A π -matching network on the top surface of the LTCC was reserved to match the input impedance. The M1 is the series element, and M2 and M3 are the shunt elements for the π -matching network. The bond wire for connecting the antenna and the DPDT switch was also kept on the module before the 50- Ω output line.

The EM simulated and measured return losses $(1/S_{11})$ are presented in Fig. 8. The measured 10-dB return-loss bandwidth is from 4.73 to 5.95 GHz, which agrees quite well with the simulated one (from 4.7 to 6.0 GHz). Fig. 9 shows the far-field normalized radiation patterns in the principal planes at 5.25 GHz. Both the measured and simulated results are shown for comparison. It is seen that they are consistent with each other and are quite omnidirectional in the x-z- and y-z-planes. The measured peak gains in the x-z-, y-z-, and x-y-planes are 0.35, 0.15, and -0.12 dBi, respectively. The average gains in these planes are correspondingly -1.32, -3.03, and -3.18 dBi.

III. INTEGRATION OF THE ANTENNA SWITCH MODULE

According to the proposed bandpass and low-pass filters, we integrated these circuits and the antenna into a package and simulated the coupling effect and isolation. We first pre-simulated each buried components, then put them together into a package,

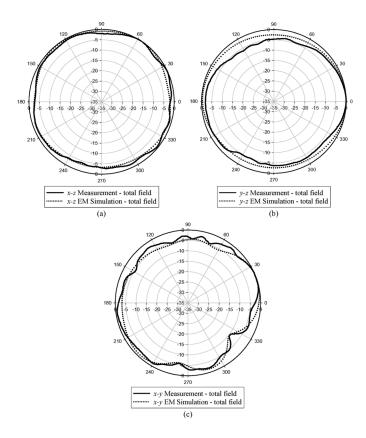
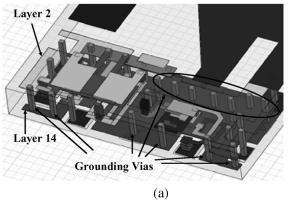
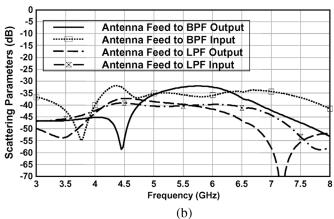


Fig. 9. EM simulated and measured far-field normalized radiation patterns in the: (a) x–z-plane, (b) y–z-plane, and (c) x–y-plane at 5.25 GHz on a PCB with a size of 55 mm \times 20 mm.

and finally fine tuned the entire antenna module. The size of this antenna switch module is merely $6.2 \text{ mm} \times 5.4 \text{ mm} \times 0.98 \text{ mm}$. 14 LTCC layers were used with seven thin layers (0.04 mm) and seven thick layers (0.09 mm). The thickness of each metal plate (silver alloy) is 0.006 mm. The second and fourteenth layers are grounding layers to shield other EM interference. As shown in Fig. 10(a), many grounding vias, connecting between the two shielding layers, were designed for equalizing the potentials of the two grounding layers and suppressing the coupling among the buried circuits. The simulated results of the couplings between the antenna port, bandpass-filter ports, and low-pass-filter ports are shown in Fig. 10(b) and (c) where "BPF input" ("LPF input") and "BPF output" ("LPF output") denote the input and output ports of the bandpass (low-pass) filters, respectively. The isolation between the antenna and two filters, and those between the filters, are all higher than 30 dB in the frequency range from 3 to 8 GHz. The simulated results show that the EM couplings among all the components in the module have been designed with negligibly small values.

The 3-D layout of the antenna switch module (module 4) is shown in Fig. 11(a). Fig. 11(b) presents a photograph of the LTCC module and indicates the metal pads on the top surface including two dc control voltage pads (Vc1 and Vc2), three grounding pads (GND3, GND4, and GND5), and two antenna pads (pad1 and Ext. Ant.). This module contains three output ports, i.e., the transmitting port (TX port), receiving port (RX





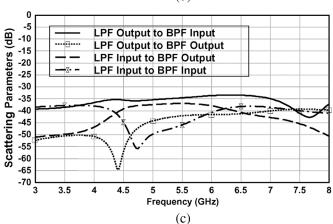
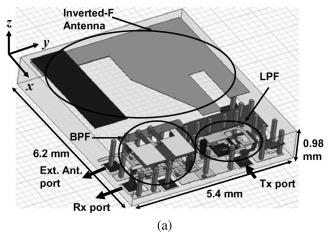


Fig. 10. (a) Grounding vias between layers 2 and 14. (b) Couplings between the antenna and filters. (c) Couplings between the low-pass filter (LPF) and the bandpass filter (BPF).

port), and external antenna port. The 0.7-mil gold wires were used as the bond wires between the DPDT switch and pads. The π -matching network was realized in between the Ant. Feed, pad3, GND1, and GND2. The SMD device (0201 size) between pad2 and pad3 is the dc-blocking capacitor. Significantly, pad1 and pad2 are connected through the buried 50- Ω transmission line in the LTCC substrate. Separating pad1 and pad2 is to avoid the surface mount solder paste adhering to pad1 and affecting the bond wire connecting from pad1 to the switch. An external antenna port (named Ext. Ant.) is reserved for antenna diversity application from which an external antenna can be connected to



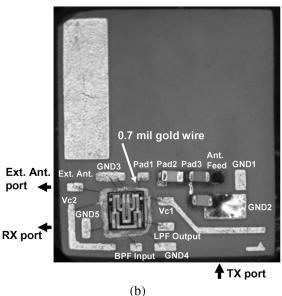


Fig. 11. (a) 3-D layout of the antenna switch module. (b) Finished antenna switch module, showing the metal pads on the top surface. GND = grounding pad, Ext. Ant. = external antenna pad, Vc = dc control voltage pad, BPF = bandpass filter, LPF = low-pass filter.

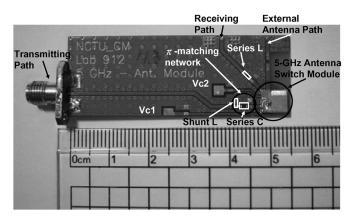


Fig. 12. Antenna switch module mounting on an FR4 evaluation board with a size of 55 mm \times 20 mm.

this front-end module. Fig. 12 shows a photograph of the fabricated LTCC antenna switch module mounting on an FR4 evaluation board with a size of $55 \text{ mm} \times 20 \text{ mm}$.

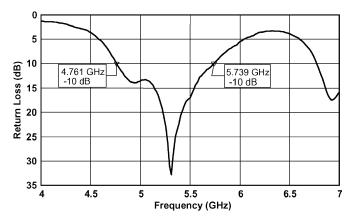


Fig. 13. Measured return loss $(1/S_{11})$ in the transmitting path of the entire antenna switch module on the small PCB with a size of 55 mm \times 20 mm.

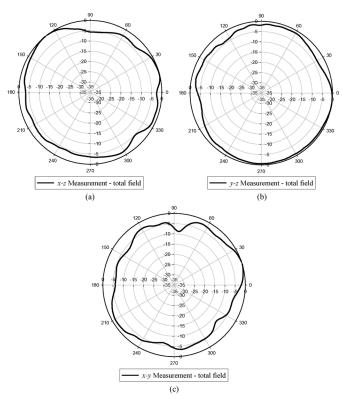


Fig. 14. Measured normalized radiation patterns in: (a) the x-z-plane, (b) y-z-plane, and (c) x-y-plane at 5.25 GHz for the transmitting path on the small PCB with size of 55 mm \times 20 mm.

The transmitting path is composed of the LPF, DPDT switch, and antenna. Moreover, a π -matching network, which includes a series capacitor (1 pF) and shunt inductor (1 nH) on the FR4 evaluation board can improve the input impedance in the transmitting path. The measured return loss in the transmitting path of the entire antenna switch module is presented in Fig. 13. The frequency range of return loss larger than 10 dB is from 4.76 to 5.73 GHz (approximately 970 MHz) with a maximum return loss of 33 dB at 5.3 GHz.

The measured normalized radiation patterns of the entire antenna switch module on the small PCB at 5.25 GHz for the transmitting path are shown in Fig. 14. It is seen that the patterns are quite omnidirectional in the three principal planes. The peak

E-Total	x-z plane	y-z plane	x-y plane
Peak Gain	0.24 dBi	-1.24 dBi	1.25 dBi
Average Gain	-2.45 dBi	-3.19 dBi	-2.91 dBi

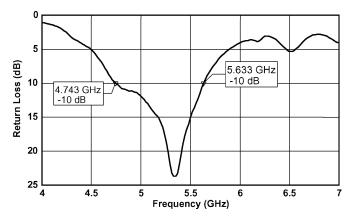


Fig. 15. Measured return loss $(1/S_{11})$ in the receiving path of the entire antenna switch module on the small PCB with a size of 55 mm \times 20 mm.

(average) gains in the x–z-, y–z-, and x–y-planes are 0.24 dBi (-2.45 dBi), -1.24 dBi (-3.19 dBi), and 1.25 dBi (-2.91 dBi), respectively. Table IV summarizes the results. Due to the integration with the circuits, these antenna gains are varied from those described earlier.

The receiving and transmitting paths share the embedded antenna and DPDT switch. The bandpass filter is included in the receiving path of the LTCC substrate. In addition, a series inductor (1 nH) is added in the receiving path on the small FR4 evaluation board to improve the input impedance. The measured return loss in the receiving path of the entire antenna switch module is presented in Fig. 15. The bandwidth of return loss larger than 10 dB is from 4.74 to 5.63 GHz (approximately 890 MHz) with a maximum return loss of 24 dB at 5.3 GHz.

Fig. 16 shows the measured normalized radiation patterns at 5.25 GHz for the receiving path, which are also omnidirectional in the three principal planes. The peak (average) gains are -1.7 dBi (-3.77 dBi), -1.89 dBi (-4.67 dBi), and -2.49 dBi (-5.10 dBi), respectively in the x-z-, y-z-, and x-y-planes. Table V summarizes the results. Due to the extra loss of the bandpass filter to the low-pass filter, the antenna gains in the receiving path are lower than those in the transmitting path.

Since the radiation of a small antenna is influenced by nearby conductors due to the induced conductor currents, the size of the grounded PCB would thus affect the radiation performance of the antenna front-end module. In order to see whether the developed antenna module can be used in a different PCB, a large PCB with a size of 80 mm \times 46 mm (the typical size for a PCMCIA WLAN card) was fabricated for testing. As shown in Fig. 17, the substrate ground of the large PCB occupies an area of (75 mm \times 46 mm + 20 mm \times 5 mm), leaving a ground-free blank area of 26 mm \times 5 mm. Note that the length (26 mm) of the blank area was determined by simulation according to an

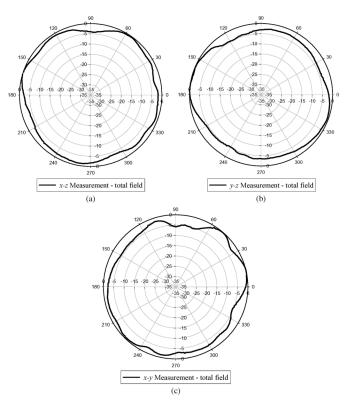
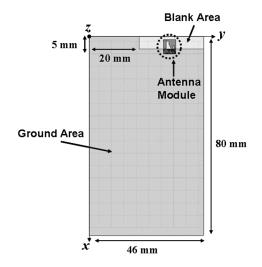


Fig. 16. Measured normalized radiation patterns in: (a) the x-z-plane, (b) y-z-plane, and (c) x-y-plane at 5.25 GHz for the receiving path on the small PCB with size of 55 mm \times 20 mm.

TABLE V PEAK AND AVERAGE GAINS IN THE RECEIVING PATH ON THE SMALL PCB WITH SIZE OF 55 mm \times 20 mm

E-Total	x-z plane	y-z plane	x-y plane
Peak Gain	-1.7 dBi	-1.89 dBi	-2.49 dBi
Average Gain	-3.77 dBi	-4.67 dBi	-5.10 dBi



 $Fig.\ 17.\ \ Geometry\ of\ the\ large\ FR4\ PCB\ containing\ the\ antenna\ switch\ module.$

optimal radiation pattern of the antenna module. A π -matching network on the large PCB with a shunt inductor (2.7 nH), a series

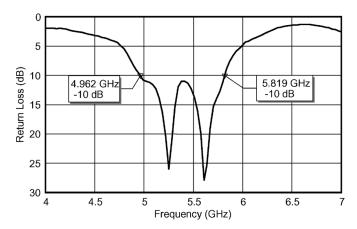


Fig. 18. Measured return loss $(1/S_{11})$ in the transmitting path of the entire antenna switch module on the large PCB with size of 80 mm \times 46 mm.

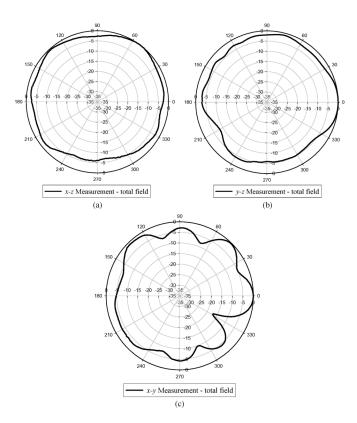


Fig. 19. Measured normalized radiation patterns in the: (a) x-z-plane, (b) y-z-plane, and (c) x-y-plane at 5.25 GHz for the transmitting path on the large PCB with a size of 80 mm \times 46 mm.

resister (0 Ω), and a shunt capacitor (0.3 pF) was used to improve the input impedance.

Fig. 18 shows the measured return loss $(1/S_{11})$ in the transmitting path of the entire antenna switch module on the large PCB. The 10-dB return-loss bandwidth is 857 MHz, ranging from 4.962 to 5.819 GHz. The measured normalized radiation patterns at 5.25 GHz in the transmitting path of the entire antenna switch module on the large PCB are shown in Fig. 19. The radiation patterns are omnidirectional in the x-z-and y-z-planes. A radiation null of -17 dB happens at 330° in

TABLE VI
PEAK AND AVERAGE GAINS IN THE TRANSMITTING PATH
ON THE LARGE PCB WITH SIZE OF 80 mm imes 46 mm

E-Total	x-z plane	y-z plane	x-y plane
Peak Gain	-0.31 dBi	-0.85dBi	-0.64 dBi
Average Gain	-3.22 dBi	-5.46 dBi	-4.2dBi

the *x*–*y*-plane. The peak and average gains are summarized in Table VI. It is seen that although the measured results are little degraded, the finished antenna front-end module still works well on the large PCB.

IV. CONCLUSION

In this paper, a compact RF front-end module using LTCC multilayer technology has been designed and realized. The module includes a BPF, an LPF, a DPDT bare die switch, and an embedded inverted-F antenna, and has a very small size of $6.2 \text{ mm} \times 5.4 \text{ mm} \times 0.98 \text{ mm}$. The effect of the bond wire has been taken into account by incorporating into the design of the filters. Both the proposed filters possess transmission zeros at out band for suppressing unwanted signals. The performances of the developed antenna front-end module on two PCBs with different sizes (55 mm \times 20 mm and 80 mm \times 46 mm) have been demonstrated. The measured radiation patterns are omnidirectional. The return-loss bandwidth and antenna gain are enough and suitable for the IEEE 802.11a application. In the future, more circuit components, such as the power amplifier, low-noise amplifier, and RF transceiver can be integrated to the LTCC module. Dual-band components (bandpass filter, antenna, and balun) can also be designed in to achieve a complete RF front-end module for the IEEE 802.11 a/b/g WLAN applications.

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